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Date

: December 2, 2008

Patent No. : 7438707
Inventor(s) : Chih-Wei Hung et al.
Issued : November 14, 2008
Title : FLASH MEMORY CELL STRUCTURE AND OPERATING METHOD THEREOF


Re: Request for Certificate of Correction

Consideration has been given your request for the issuance of a certificate of correction.

Review of the application file has revealed the omission of the Foreign Priority data on the printed patent as a result of applicant's failure to fully comply with 35 U.S.C. 119, in that conditional requirements were not met. Applicant's attention is directed to MPEP 201.14(a), 37 CFR 1.17(i).

In view of the forgoing, applicant's request in this matter is hereby denied.

Any telephone inquiry concerning this communication should be directed to Ms. A. Green at (703) 308-9380 ext. 123.


Mary Diggs, Supervisor
Decisions & Certificates
of Correction Branch

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